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Vishay Semiconductor/Diodes Division HFA12PA120C

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite



Datasheet of HFA12PA120C - DIODE ARRAY GP 1200V 6A TO247AC Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



HFA12PA120C

Vishay High Power Products

HEXFRED[®] Ultrafast Soft Recovery Diode, 2 x 6 A

3

Anode

FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Specified at operating conditions
- Designed and qualified for industrial level

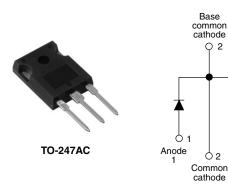
BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

HFA12PA120C is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. The HFA12PA120C has basic ratings of 1200 V and 6 A per leg continuous current. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current ($I_{\mbox{\scriptsize RBM}}$) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA12PA120C is ideally suited for applications in power supplies and power conversion systems (such as inverters, converters, UPS systems, and power factor correction circuits), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		1200	V	
Maximum continuous forward current per leg		T _C = 100 °C	6		
per device			12	А	
Single pulse forward current	I _{FSM}		80	A	
Maximum repetitive forward current	I _{FRM}		24		
Maximum nower dissinction	PD	T _C = 25 °C	62.5	W	
Maximum power dissipation		T _C = 100 °C	25	vv	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	



PRODUCT SUMMARY				
V _R	1200 V			
V _F at 6 A at 25 °C	3.0 V			
I _{F(AV)}	2 x 6 A			
t _{rr} (typical)	26 ns			
T _J (maximum)	150 °C			
Q _{rr} (typical)	116 nC			
dl _{(rec)M} /dt (typical) at 125 °C	100 A/µs			
I _{RRM} (typical)	4.4 A			

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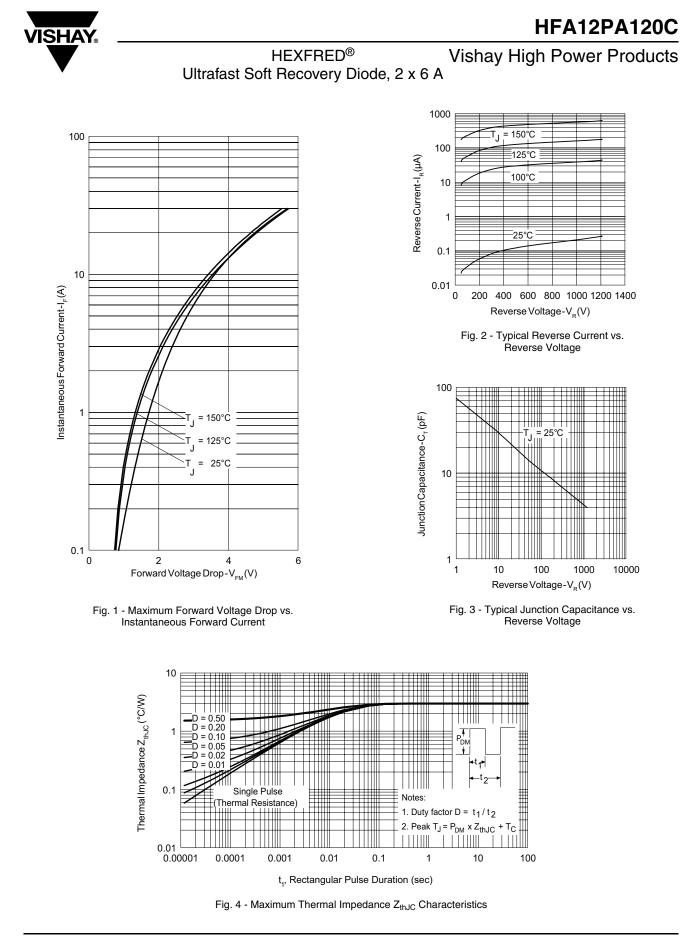
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ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-	
Maximum forward voltage V _{FM}		I _F = 6 A	-	2.7	3.0	V
	V _{FM}	I _F = 12 A	-	3.5	3.9	
		I _F = 6 A, T _J = 125 °C	-	2.4	2.8	
Maximum reverse I _{RM}		$V_R = V_R$ rated	-	0.26	5.0	
		T_J = 125 °C, V_R = 0.8 x V_R rated	-	110	500	μΑ
Junction capacitance	CT	V _R = 200 V	-	9.0	14	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8.0 -		-	nH	

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	26	-	
Reverse recovery time	t _{rr1}	T _J = 25 °C		-	53	80	ns
	t _{rr2}	T _J = 125 °C		-	87	130	
Peak recovery current	I_{RRM1} $T_{\text{J}} = 25 \text{ °C}$		-	4.4	8.0	A	
Feak recovery current	I _{RRM2}	T _J = 125 °C		5.0	9.0		
Reverse recovery charge	Q _{rr1}	T _J = 25 °C	dl _F /dt = 200 A/μs V _R = 200 V	-	116	320	nC
neverse recovery charge	Q _{rr2}	T _J = 125 °C		-	233	585	
Peak rate of fall of recovery	dI _{(rec)M} /dt1	T _J = 25 °C		-	180	-	- A/μs
current during t _b	dI _{(rec)M} /dt2	T _J = 125 °C		-	100	-	-7/μ5

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	2.0	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.50	-	
Weight			-	2.0	-	g
weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)
Marking device		Case style TO-247AC (JEDEC)	HFA12PA120C			







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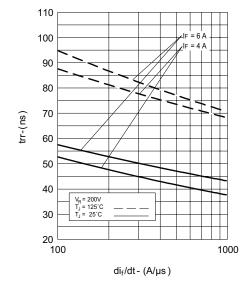


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

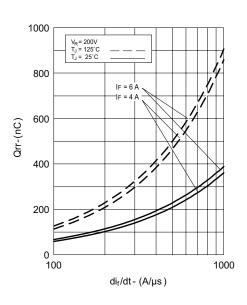


Fig. 7 - Typical Stored Charge vs. dI_F/dt

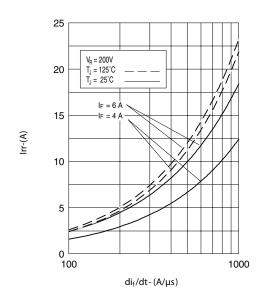


Fig. 6 - Typical Recovery Current vs. $\mathrm{dI}_\mathrm{F}/\mathrm{dt}$

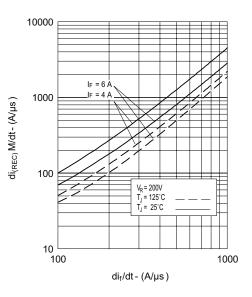


Fig. 8 - Typical dl_{(rec)M}/dt vs. dl_F/dt





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 $V_{R} = 200 V$ $L = 70 \mu H$ D.U.T. $U_{R} = 200 V$ D.U.T. $D_{R} = 200 V$ D.U.T.

Fig. 9 - Reverse Recovery Parameter Test Circuit

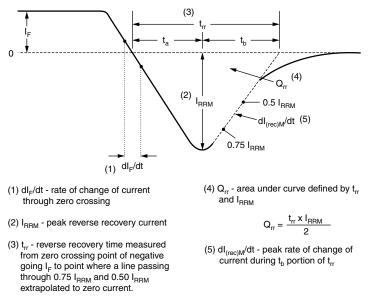


Fig. 10 - Reverse Recovery Waveform and Definitions



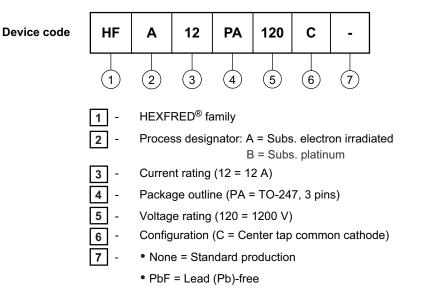
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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95223				
Part marking information	http://www.vishay.com/doc?95226			





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